



3.3V CMOS OCTAL EDGE-TRIGGERED D-TYPE FLIP-FLOP WITH 3-STATE OUTPUTS, 5 VOLT TOLERANT I/O AND BUS-HOLD

IDT74LVCH574A

FEATURES:

- 0.5 MICRON CMOS Technology
- ESD > 2000V per MIL-STD-883, Method 3015; > 200V using machine model (C = 200pF, R = 0)
- 1.27mm pitch SOIC, 0.65mm pitch SSOP, 0.635mm pitch QSOP, 0.65mm pitch TSSOP packages
- Extended commercial range of -40°C to +85°C
- $V_{CC} = 3.3V \pm 0.3V$, Normal Range
- $V_{CC} = 2.3V$ to $3.6V$, Extended Range
- CMOS power levels ($0.4\mu W$ typ. static)
- Rail-to-Rail output swing for increased noise margin
- All inputs, outputs and I/O are 5 Volt tolerant
- Supports hot insertion

Drive Features for LVCH574A:

- High Output Drivers: $\pm 24mA$
- Reduced system switching noise

APPLICATIONS:

- 5V and 3.3V mixed voltage systems
- Data communication and telecommunication systems

DESCRIPTION:

The LVCH574A octal edge-triggered D-type flip-flop is built using advanced dual-metal CMOS technology. The device features 3-state outputs designed specifically for driving highly capacitive or relatively low-impedance loads. The LVCH574A is particularly suitable for implementing buffer registers, input-output (I/O) ports, bidirectional bus drivers, and working registers.

On the positive transition of the clock (CLK) input, the Q outputs are set to the logic levels at the data (D) inputs.

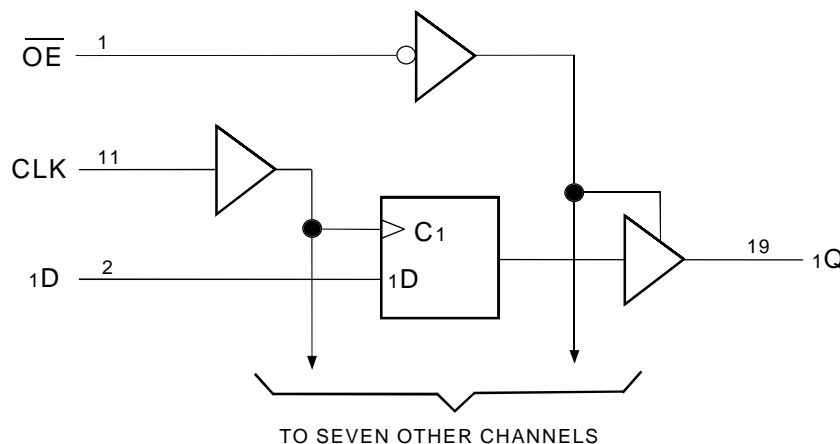
A buffered output-enable (\overline{OE}) input can be used to place the eight outputs in either a normal logic state (high or low logic levels) or a high-impedance state. In the high-impedance state, the outputs neither load nor drive the bus lines significantly. \overline{OE} does not affect the internal operations of the flip-flops. Old data can be retained or new data can be entered while the outputs are in the high-impedance state.

The LVCH574A has been designed with a $\pm 24mA$ output driver. This driver is capable of driving a moderate to heavy load while maintaining speed performance.

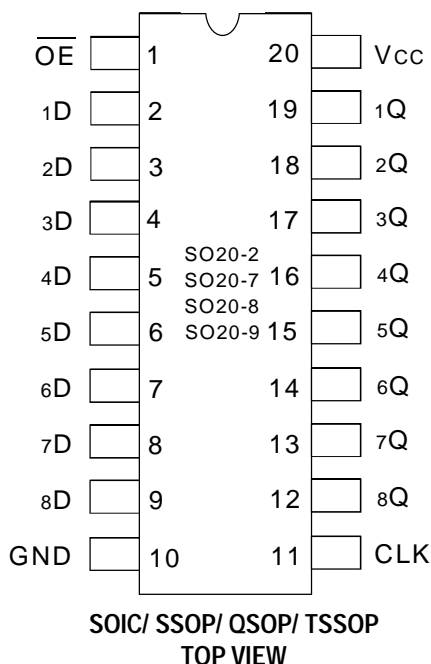
Inputs can be driven from either 3.3V or 5V devices. This feature allows the use of this device as a translator in a mixed 3.3V/5V system environment.

The LVCH574A has "bus-hold" which retains the inputs' last state whenever the input goes to a high impedance. This prevents floating inputs and eliminates the need for pull-up/down resistors.

FUNCTIONAL BLOCK DIAGRAM



PIN CONFIGURATION



PIN DESCRIPTION

Pin Names	Description
\overline{OE}	Output-enable Input (Active LOW)
CLK	Clock Input
xD	Data Inputs ⁽¹⁾
xQ	3-State Outputs

NOTE:

- These pins have "Bus-hold". All other pins are standard inputs, outputs, or I/Os.

ABSOLUTE MAXIMUM RATINGS ⁽¹⁾

Symbol	Description	Max.	Unit
$V_{TERM}^{(2)}$	Terminal Voltage with Respect to GND	- 0.5 to +6.5	V
$V_{TERM}^{(3)}$	Terminal Voltage with Respect to GND	- 0.5 to +6.5	V
TSTG	Storage Temperature	- 65 to +150	°C
I_{OUT}	DC Output Current	- 50 to +50	mA
I_{IK} I_{OK}	Continuous Clamp Current, $V_I < 0$ or $V_O < 0$	- 50	mA
I_{CC} I_{SS}	Continuous Current through each V_{CC} or GND	±100	mA

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NOTES:

- Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.
- V_{CC} terminals.
- All terminals except V_{CC} .

CAPACITANCE ($T_A = +25^\circ\text{C}$, $f = 1.0\text{MHz}$)

Symbol	Parameter ⁽¹⁾	Conditions	Typ.	Max.	Unit
C_{IN}	Input Capacitance	$V_{IN} = 0V$	4.5	6	pF
C_{OUT}	Output Capacitance	$V_{OUT} = 0V$	5.5	8	pF
$C_{I/O}$	I/O Port Capacitance	$V_{IN} = 0V$	6.5	8	pF

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NOTE:

- As applicable to the device type.

FUNCTION TABLE (each flip-flop) ⁽¹⁾

Inputs			Outputs
\overline{OE}	CLK	xD	xQ
L	↑	H	H
L	↑	L	L
L	H or L	X	Q_0
H	X	X	Z

NOTE:

- H = HIGH Voltage Level
L = LOW Voltage Level
X = Don't Care
Z = High-Impedance
↑ = LOW-to-HIGH Transition
 Q_0 = Level of Q before the indicated steady-state input conditions were established.

DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

Following Conditions Apply Unless Otherwise Specified:

Operating Condition: $T_A = -40^{\circ}\text{C}$ To $+85^{\circ}\text{C}$

Symbol	Parameter	Test Conditions		Min.	Typ. ⁽¹⁾	Max.	Unit
V_{IH}	Input HIGH Voltage Level	$V_{CC} = 2.3\text{V to } 2.7\text{V}$		1.7	—	—	V
		$V_{CC} = 2.7\text{V to } 3.6\text{V}$		2	—	—	
V_{IL}	Input LOW Voltage Level	$V_{CC} = 2.3\text{V to } 2.7\text{V}$		—	—	0.7	V
		$V_{CC} = 2.7\text{V to } 3.6\text{V}$		—	—	0.8	
I_{IH} I_{IL}	Input Leakage Current	$V_{CC} = 3.6\text{V}$	$V_I = 0 \text{ to } 5.5\text{V}$	—	—	± 5	μA
I_{OZH} I_{OZL}	High Impedance Output Current (3-State Output pins)	$V_{CC} = 3.6\text{V}$	$V_O = 0 \text{ to } 5.5\text{V}$	—	—	± 10	μA
I_{OFF}	Input/Output Power Off Leakage	$V_{CC} = 0\text{V}, V_{IN} \text{ or } V_O \leq 5.5\text{V}$		—	—	± 50	μA
V_{IK}	Clamp Diode Voltage	$V_{CC} = 2.3\text{V}, I_{IN} = -18\text{mA}$		—	-0.7	-1.2	V
V_H	Input Hysteresis	$V_{CC} = 3.3\text{V}$		—	100	—	mV
I_{CCL} I_{CCH} I_{CCZ}	Quiescent Power Supply Current	$V_{CC} = 3.6\text{V}$	$V_{IN} = \text{GND or } V_{CC}$	—	—	10	μA
			$3.6 \leq V_{IN} \leq 5.5\text{V}^{(2)}$	—	—	10	
ΔI_{CC}	Quiescent Power Supply Current Variation	One input at $V_{CC} - 0.6\text{V}$, other inputs at V_{CC} or GND		—	—	500	μA

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NOTES:

1. Typical values are at $V_{CC} = 3.3\text{V}$, $+25^{\circ}\text{C}$ ambient.
2. This applies in the disabled state only.

BUS-HOLD CHARACTERISTICS

Symbol	Parameter ⁽¹⁾	Test Conditions		Min.	Typ. ⁽²⁾	Max.	Unit
I_{BHH} I_{BHL}	Bus-Hold Input Sustain Current	$V_{CC} = 3.0\text{V}$	$V_I = 2.0\text{V}$	-75	—	—	μA
			$V_I = 0.8\text{V}$	75	—	—	
I_{BHH} I_{BHL}	Bus-Hold Input Sustain Current	$V_{CC} = 2.3\text{V}$	$V_I = 1.7\text{V}$	—	—	—	μA
			$V_I = 0.7\text{V}$	—	—	—	
I_{BHHO} I_{BHLO}	Bus-Hold Input Overdrive Current	$V_{CC} = 3.6\text{V}$	$V_I = 0 \text{ to } 3.6\text{V}$	—	—	± 500	μA

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NOTES:

1. Pins with Bus-hold are identified in the pin description.
2. Typical values are at $V_{CC} = 3.3\text{V}$, $+25^{\circ}\text{C}$ ambient.

OUTPUT DRIVE CHARACTERISTICS

Symbol	Parameter	Test Conditions ⁽¹⁾		Min.	Max.	Unit
VOH	Output HIGH Voltage	VCC = 2.3V to 3.6V	IOH = - 0.1mA	VCC - 0.2	—	V
		VCC = 2.3V	IOH = - 6mA	2	—	
		VCC = 2.3V	IOH = - 12mA	1.7	—	
		VCC = 2.7V		2.2	—	
		VCC = 3.0V		2.4	—	
		VCC = 3.0V	IOH = - 24mA	2.2	—	
VOL	Output LOW Voltage	VCC = 2.3V to 3.6V	IOL = 0.1mA	—	0.2	V
		VCC = 2.3V	IOL = 6mA	—	0.4	
			IOL = 12mA	—	0.7	
		VCC = 2.7V	IOL = 12mA	—	0.4	
		VCC = 3.0V	IOL = 24mA	—	0.55	

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NOTE:

1. VIH and VIL must be within the min. or max. range shown in the DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE table for the appropriate VCC range. TA = - 40°C to +85°C.

OPERATING CHARACTERISTICS, TA = 25°C

Symbol	Parameter	Test Conditions	VCC = 2.5V±0.2V	VCC = 3.3V±0.3V	Unit
			Typical	Typical	
CPD	Power Dissipation Capacitance per Flip-Flop Outputs enabled	CL = 0pF, f = 10Mhz	—	43	pF
CPD	Power Dissipation Capacitance per Flip-Flop Outputs disabled		—	15	pF

SWITCHING CHARACTERISTICS ⁽¹⁾

Symbol	Parameter	VCC = 2.5V±0.2V		VCC = 2.7V		VCC = 3.3V±0.3V		Unit
		Min.	Max.	Min.	Max.	Min.	Max.	
tPLH tPHL	Propagation Delay CLK to xQ	—	—	—	8	2.2	7	ns
tPLH tPHL	Output Enable Time OE to xQ	—	—	—	8.5	1.5	7.5	ns
tPLH tPHL	Output Disable Time OE to xQ	—	—	—	7	1.7	6.4	ns
tw	Pulse Duration, CLK HIGH or LOW	—	—	3.3	—	3.3	—	ns
tsu	Setup Time Data before CLK↑	—	—	2	—	2	—	ns
th	Hold Time, data after CLK↑	—	—	1.5	—	1.5	—	ns
tsk(0)	Output Skew ⁽²⁾	—	—	—	—	—	500	ps

NOTES:

1. See test circuits and waveforms. TA = - 40°C to + 85°C.
2. Skew between any two outputs of the same package and switching in the same direction.

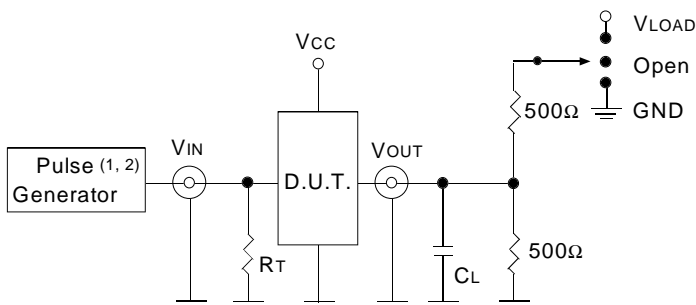
TEST CIRCUITS AND WAVEFORMS

TEST CONDITIONS

Symbol	V _{CC} (1) = 3.3V ± 0.3V	V _{CC} (1) = 2.7V	V _{CC} (2) = 2.5V ± 0.2V	Unit
V _{LOAD}	6	6	2 x V _{CC}	V
V _{IH}	2.7	2.7	V _{CC}	V
V _T	1.5	1.5	V _{CC} / 2	V
V _{LZ}	300	300	150	mV
V _{HZ}	300	300	150	mV
C _L	50	50	30	pF

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TEST CIRCUITS FOR ALL OUTPUTS



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DEFINITIONS:

C_L = Load capacitance: includes jig and probe capacitance.

R_T = Termination resistance: should be equal to Z_{OUT} of the Pulse Generator.

NOTES:

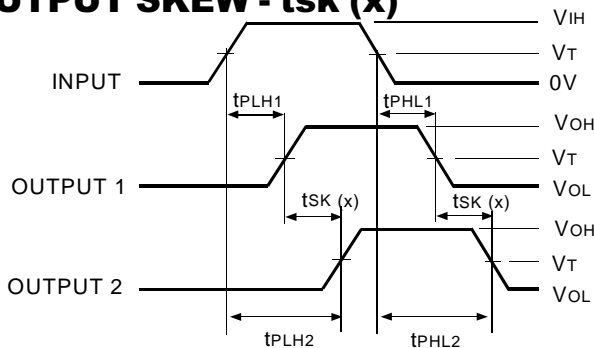
1. Pulse Generator for All Pulses: Rate ≤ 10MHz; t_F ≤ 2.5ns; t_R ≤ 2.5ns.
2. Pulse Generator for All Pulses: Rate ≤ 10MHz; t_F ≤ 2ns; t_R ≤ 2ns.

SWITCH POSITION

Test	Switch
Open Drain	V _{LOAD}
Disable Low	
Enable Low	
Disable High	GND
Enable High	
All Other tests	Open

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OUTPUT SKEW - t_{SK}(x)



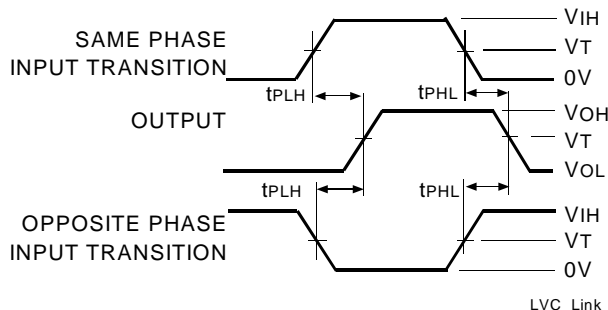
$$t_{SK}(x) = |t_{PLH2} - t_{PLH1}| \text{ or } |t_{PHL2} - t_{PHL1}|$$

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NOTES:

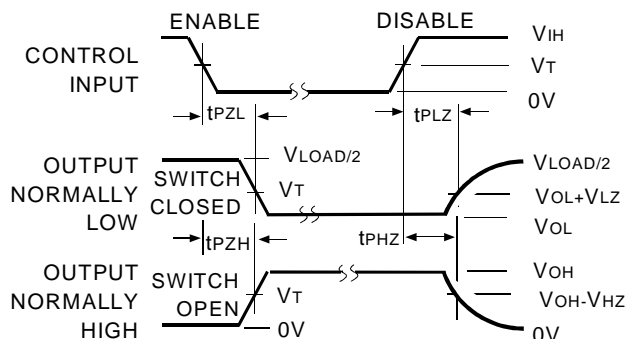
1. For t_{SK}(o) OUTPUT1 and OUTPUT2 are any two outputs.
2. For t_{SK}(b) OUTPUT1 and OUTPUT2 are in the same bank.

PROPAGATION DELAY



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ENABLE AND DISABLE TIMES

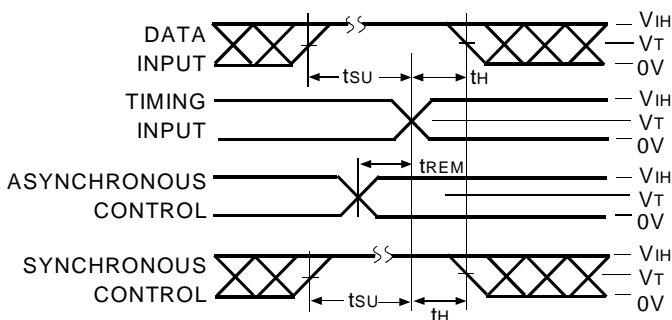


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NOTE:

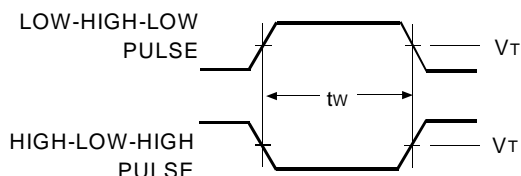
1. Diagram shown for input Control Enable-LOW and input Control Disable-HIGH.

SET-UP, HOLD, AND RELEASE TIMES



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PULSE WIDTH



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ORDERING INFORMATION

IDT	XX	LVC	X	XXXX	XX	
Temp. Range		Bus-Hold	Device Type	Package		
					SO	Small Outline IC (gull wing) (SO20-2)
					PY	Shrink Small Outline Package (SO20-7)
					Q	Quarter Size Small Outline Package (SO20-8)
					PG	Thin Shrink Small Outline Package (SO20-9)
				574A		Octal Edge-Triggered D-Type Flip-Flop with 3-State Outputs, $\pm 24\text{mA}$
				H		Bus-hold
				74		-40°C to $+85^{\circ}\text{C}$



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